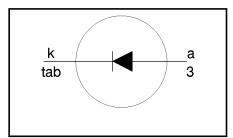
BYV79EB series

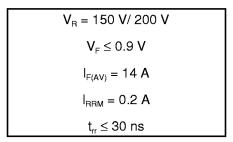
FEATURES

- · Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- · Reverse surge capability
- High thermal cycling performanceLow thermal resistance

SYMBOL



QUICK REFERENCE DATA



GENERAL DESCRIPTION

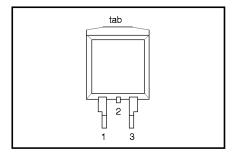
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV79EB series is supplied in the surface mounting SOT404 package.

PINNING

PIN	N DESCRIPTION		
1	no connection		
2	cathode 1		
3	anode		
tab	cathode		

SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V _{RRM} V _{RWM} V _R	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage	$\label{eq:Tmb} \textbf{BYV79EB}$ $\label{eq:Tmb} T_{mb} \leq 145^{\circ} \textbf{C}$	1 1 1	-150 150 150 150	-200 200 200 200	<<<
I _{F(AV)}	Average rectified forward current ² Repetitive peak forward current	square wave $\delta = 0.5$; $T_{mb} \le 120$ °C	-		4 8	A
I _{FSM}	per diode Non-repetitive peak forward current	$T_{mb} \le 120 ^{\circ}\text{C}$ t = 10 ms t = 8.3 ms	-	15	50 50	A
 _{RRM} _{RSM}	Repetitive peak reverse current Non-repetitive peak reverse	sinusoidal; with reapplied $V_{\text{RRM}(\text{max})}$ $t_p = 2 \ \mu \text{s}; \ \delta = 0.001$ $t_p = 100 \ \mu \text{s}$		0		A A
$T_{stg} \ T_{j}$	Storage temperature Operating junction temperature		-40 -		50 50	Ĵ.

- 1. It is not possible to make connection to pin 2 of the SOT404 package
- 2. Neglecting switching and reverse current losses.

ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _C	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	1	8	kV

BYV79EB series

THERMAL RESISTANCES

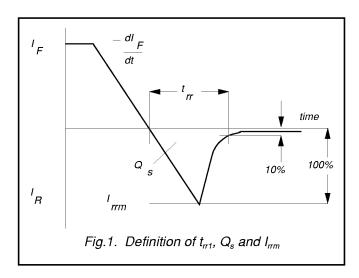
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to		-	-	2	K/W
R _{th j-a}	mounting base Thermal resistance junction to ambient	minimum footprint, FR4 board	-	50	-	K/W

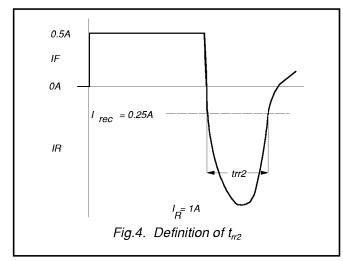
ELECTRICAL CHARACTERISTICS

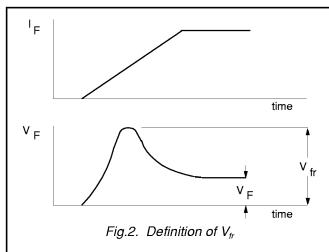
 $T_j = 25$ °C unless otherwise stated

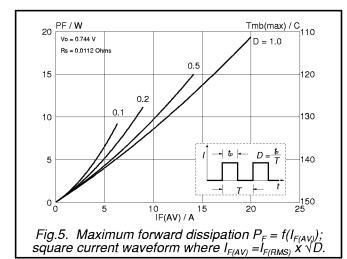
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{\scriptscriptstyle F}$	Forward voltage	$I_F = 14 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.83	0.90	V
'		$I_F = 14 \text{ A}$	-	0.95	1.05	V
		$I_{\rm F} = 50 \text{A}$	-	1.2	1.4	V
l _B	Reverse current	$\dot{V}_{R} = V_{RRM}$; $T_{j} = 100 ^{\circ}C$	-	0.5	1.3	mA
''		$V_{\rm R} = V_{\rm RBM}$	-	5	50	μ A nC
Q _s	Reverse recovery charge	$ I_{E} = 2 \text{ A}; V_{B} \ge 30 \text{ V}; -dI_{E}/dt = 20 \text{ A/}\mu\text{s} $	-	6	15	'nC
t _{rr1}	Reverse recovery time	$I_{\rm F} = 1 \text{ A}; V_{\rm B} \ge 30 \text{ V};$	-	20	30	ns
	•	-dl _F /dt = 100 A /μs				
t _{rr2}	Reverse recovery time	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A}; I_{rec} = 0.25 \text{ A}$	-	13	22	ns
$V_{\rm fr}$	Forward recovery voltage	$I_{F} = 1 \text{ A}; dI_{F}/dt = 10 \text{ A}/\mu \text{ s}$	-	1	-	V

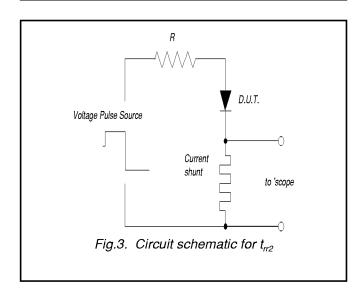
BYV79EB series











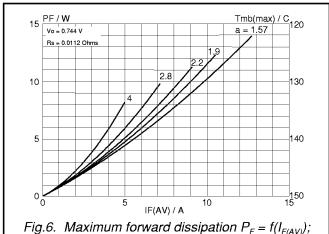
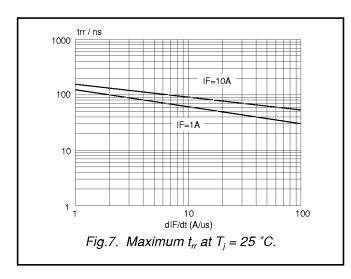
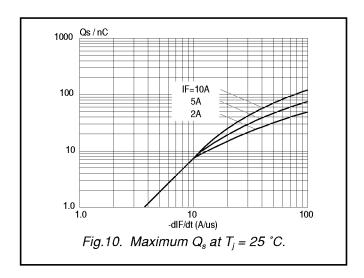
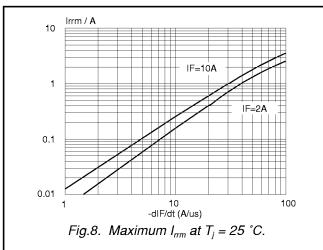


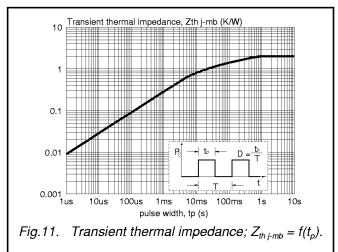
Fig.6. Maximum forward dissipation $P_F = f(I_{F(AV)})$; sinusoidal current waveform where a = form factor = $I_{F(RMS)} / I_{F(AV)}$.

BYV79EB series









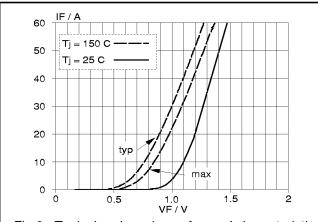
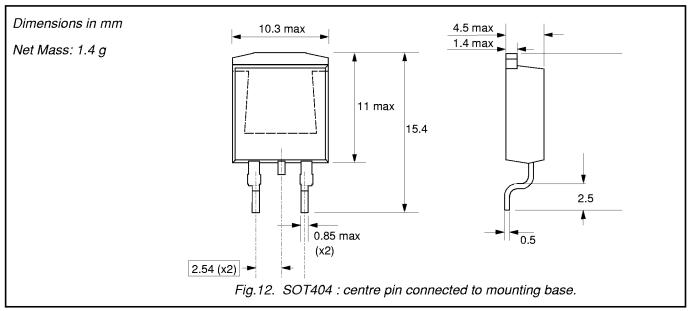


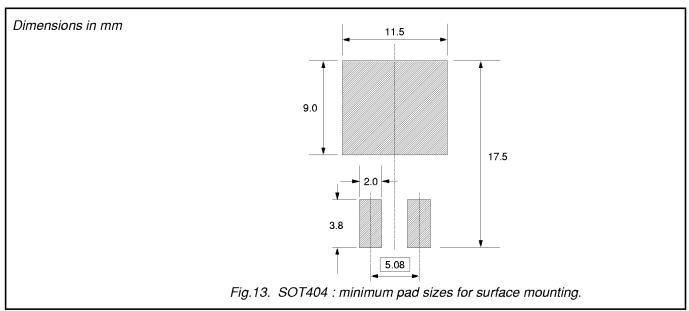
Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

BYV79EB series

MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

Rectifier diodes ultrafast, rugged

BYV79EB series

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
Limiting values				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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Philips Semiconductors Product specification

Rectifier diodes ultrafast, rugged

BYV79EB series

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